



SSCE5V082N1

1-Line Bidirectional Micro Packaged TVS Diodes for ESD Protection

• Description

The SSCE5V0B2N1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The SSCE5V0B2N1 complies with the IEC 61000-4-2 (ESD) with ±30 kV air and ±30 kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size and high ESD surge protection make SSCE5V0B2N1 an ideal choice to protect cell phone, digital cameras, and many other portable applications.







Marking

• Applications

- ♦ Cellular Handsets and Accessories
- ♦ Notebooks and Handhelds
- ♦ Portable Instrumentation
- Digital Cameras
- ♦ Peripherals
- ♦ Audio Players
- ♦ Keypads, Side Keys, USB, LDC Displays

• Mechanical data

- ♦ Lead finish:100% matte Sn (Tin)
- ♦ Mounting position: Any
- ♦ Qualified max reflow temperature:260°C
- Device meets MSL 3 requirements
- \diamond Pure tin plating: 7 ~ 17 um
- ♦ Pin flatness: ≤3mil

- \diamond 210W peak pulse power (t_P = 8/20µs)
- ♦ DFN1006-2L Package
- ♦ Working voltage: 5.0V
- ♦ Low clamping voltage
- ♦ Low capacitance (Max value:1.55pF)
- $\diamond \quad \text{Low clamping voltage} \\$
- ♦ RoHS compliant
- ♦ Complies with following standards: -IEC61000-4-2(ESD) ±30kV(contact), ±30kV(air)

-IEC61000-4-5 (Lightning) 15A (8/20µs)

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• Electronic Parameter

| Symbol | Parameter | |
|------------------|--|--|
| V _{RWM} | Peak Reverse Working Voltage | |
| I _R | Reverse Leakage Current @ V _{RWM} | |
| V _{BR} | Breakdown Voltage @ I _T | |
| Ι _T | Test Current | |
| I _{PP} | Maximum Reverse Peak Pulse Current | |
| Vc | Clamping Voltage @ IPP | |
| P _{PP} | Peak Pulse Power | |



● Absolute maximum rating @T_A=25℃

| Parameter | Symbol | Value | Unit | |
|--|-------------|----------|------|--|
| Peak Pulse Power (8/20µs) | Ppp | 210 | W | |
| Peak Pulse Current (8/20µs) | I PP | 15 | А | |
| ESD Rating per IEC61000-4-2: Contact | | 30 | K)/ | |
| Air | VESD | 30 | ۲V | |
| Storage Temperature | Tstg | -55/+150 | °C | |
| Operating Temperature | TJ | -55/+125 | °C | |
| Lead Solder Temperature – Maximum (10 Second Duration) | T∟ | 260 | °C | |

• Electrical Characteristics @T_A=25°C

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|----------------------------------|----------------|--|------|------|------|-------|
| Peak Reverse Working Voltage | VRWM | | | | 5 | V |
| Breakdown Voltage | V_{BR} | I⊤ = 1mA | 6 | 7.5 | | V |
| Reverse Leakage Current | I _R | $V_{RWM} = 5V$ | | 1 | 50 | nA |
| Clomping Voltogo ³ | Vcl | I _{PP} = 1A, t _P = 8/20us | | 8 | | V |
| | | I _{PP} = 15A, t _P = 8/20us | | 12 | 14 | V |
| Clamping Voltage ¹⁾ | Vcl | I _{PP} = 16A, t _P = 100ns | | 12 | | V |
| Dynamic resistance ¹⁾ | Rdyn | | | 0.3 | | Ω |
| Clamping Voltage ²⁾ | Vcl | $V_{ESD} = 8kV$ | | 9 | | V |
| Junction Capacitance | CJ | $V_R = 0V$, f = 1MHz | | 1.35 | 1.55 | рF |

Notes:

1) TLP parameter: Z0 = 50Ω, tp = 100ns, tr = 2ns, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

2) Contact discharge mode, according to IEC61000-4-2.

3) Non-repetitive current pulse, according to IEC61000-4-5.



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• Typical Performance Characteristics



Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

8/20µs Pulse Waveform



Package Information

Ordering Information

| Device | Package | Qty per Reel | Reel Size |
|-------------|------------|--------------|-----------|
| SSCE5V0B2N1 | DFN1006-2L | 10000 | 7 Inch |

Mechanical Data

Case: DFN1006-2L Case Material: Molded Plastic. UL Flammability



| DIM | Millimeters | | | |
|-----|-------------|------|--|--|
| DIN | Min | Мах | | |
| Α | 0.45 | 0.55 | | |
| A1 | 0.00 | 0.05 | | |
| D | 0.55 | 0.65 | | |
| Е | 0.95 | 1.05 | | |
| b | 0.45 | 0.60 | | |
| е | 0.65TYP | | | |
| L | 0.2 | 0.3 | | |
| L1 | 0.05REF | | | |

Recommended Pad outline (Unit: mm)





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